



M.S.KENNEDY CORP.

75 VOLT 10 AMP MOSFET H-BRIDGE PWM MOTOR DRIVER/AMPLIFIER

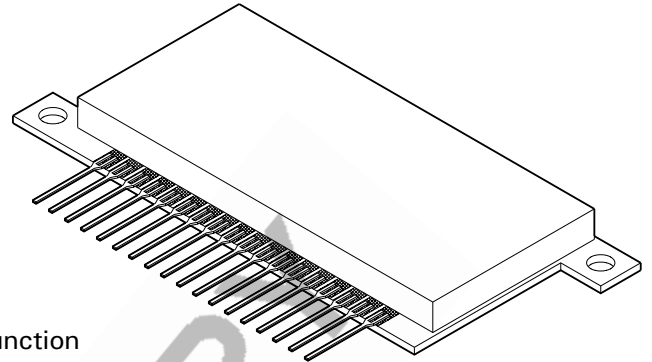
4224

8170 Thompson Road Cicero, N.Y. 13039

(315) 699-9201

FEATURES:

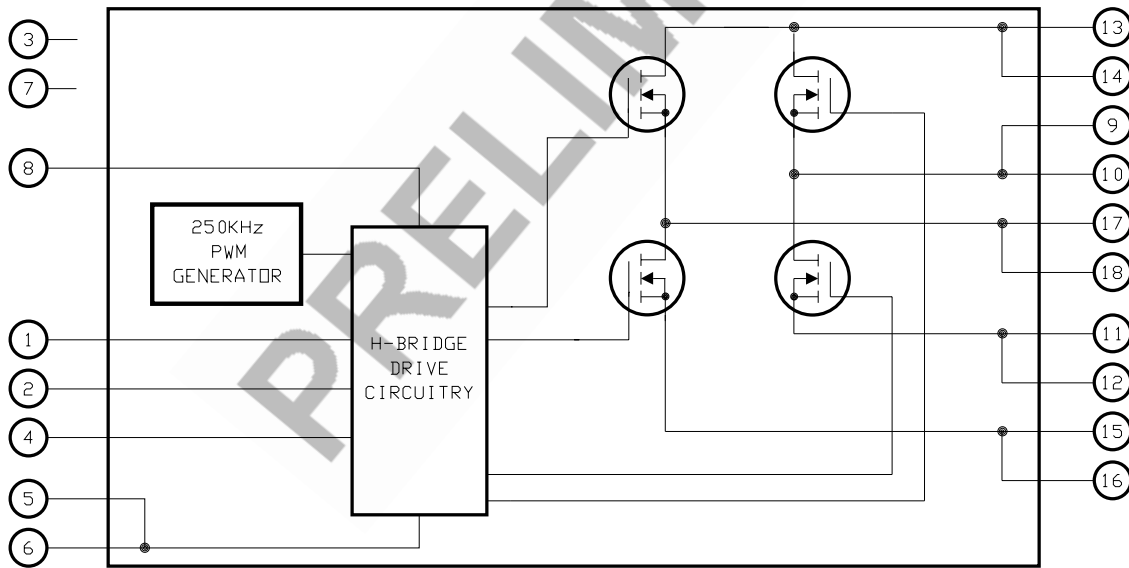
- Low RDS(ON) 0.020Ω Typical
- Low Cost Complete H-Bridge
- 10 Amp Capability, 75 Volt Maximum Rating
- Self-contained Smart Lowside/Highside Drive Circuitry
- Internal 250KHz PWM Generation, Shoot-through Protection
- Isolated Case Allows Direct Heatsinking
- Four Quadrant Operation, Torque Control Capability
- Logic Level Disable Input
- Logic Level High Side Enable Input for Special Modulation or Function



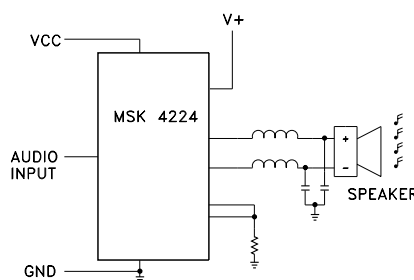
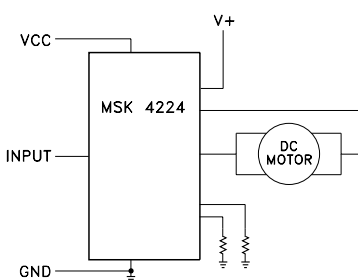
DESCRIPTION:

The MSK 4224 is a complete H-Bridge circuit to be used for DC brushed motor control or Class D switchmode amplification. All of the drive/control circuitry for the lowside and highside switches are internal to the circuit. The 250KHz PWM circuitry is internal as well, leaving the user to only provide an analog signal for the motor speed/direction, or audio signal for switchmode audio amplification. The MSK 4224 is constructed on a space efficient ceramic coated insulated metal substrate that can be directly connected to a heatsink.

EQUIVALENT SCHEMATIC



TYPICAL APPLICATIONS



PIN-OUT INFORMATION

1 HEN	18 Output B
2 Disable	17 Output B
3 N/C	16 Rsense B
4 Input	15 Rsense B
5 Ground	14 V +
6 Ground	13 V +
7 N/C	12 Rsense A
8 Vcc	11 Rsense A
9 Output A	10 Output A

ABSOLUTE MAXIMUM RATINGS

V ₊ High Voltage Supply	75V	T _{ST} Storage Temperature Range	-65°C to +150°C
V _{CC} Logic Supply	16V	T _{LD} Lead Temperature Range	300°C
I _{OUT} Continuous Output Current.....	10A	(10 Seconds)	
I _{PK} Peak Output Current	20A	T _C Case Operating Temperature	
V _{OUT} Output Voltage Range	GND -2V min. to V + max.	MSK4224	-25°C to +125°C
θ _{JC} Thermal Resistance5.3°C/W	T _J Junction Temperature	+150°C
(Output Switches)			

ELECTRICAL SPECIFICATIONS

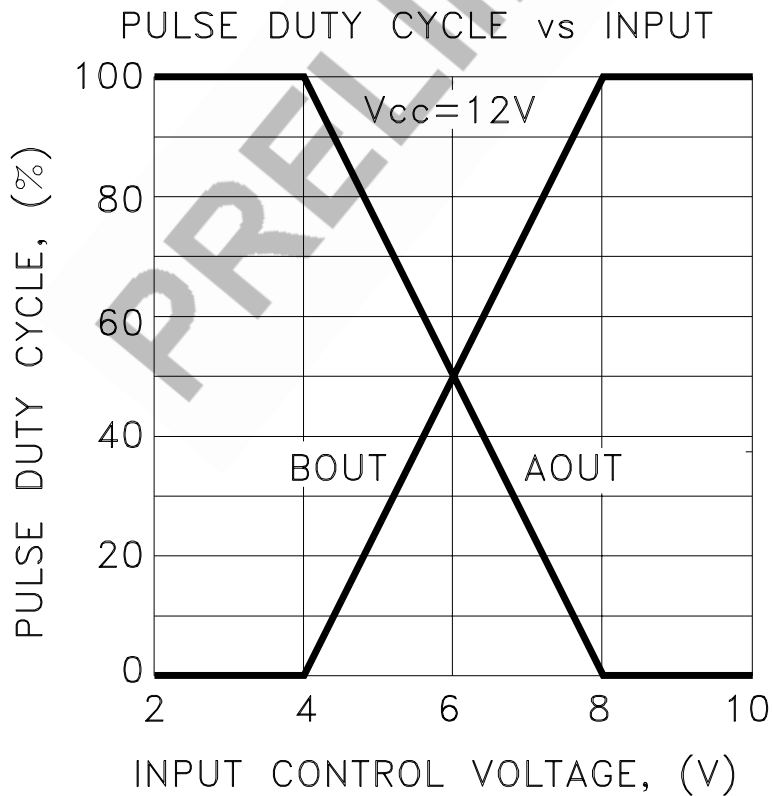
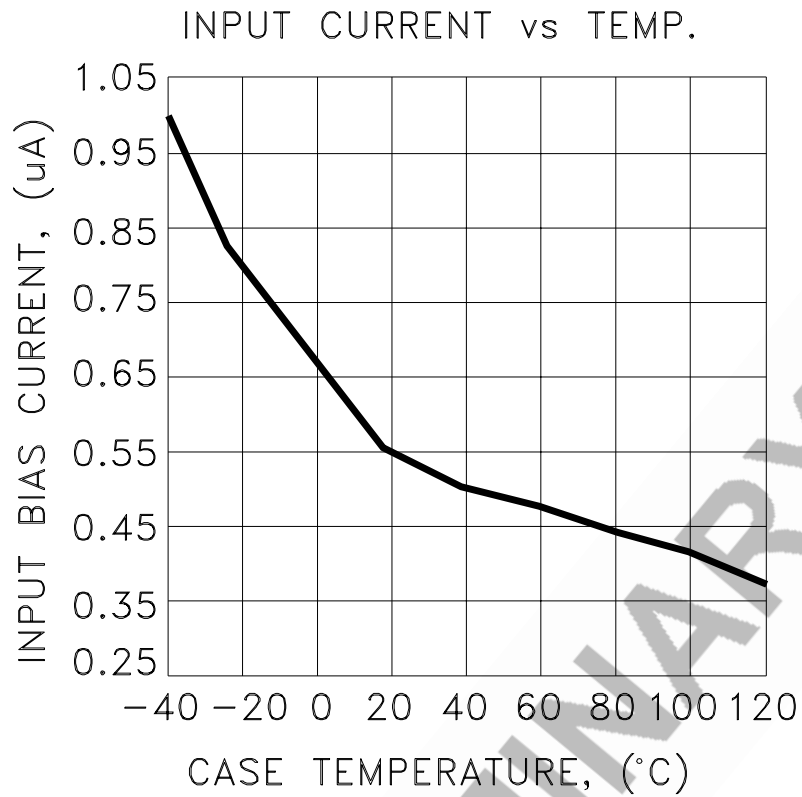
All Ratings: T_c = +25°C Unless Otherwise Specified

Parameter	Test Conditions	MSK 4224			Units
		Min.	Typ.	Max.	
OUTPUT CHARACTERISTICS					
R _{DS (ON)} ④	Each MOSFET I _D = 10A	-	-	0.013	Ω
V _{DS(ON)} Voltage ①	Each MOSFET I _D = 10A ③	-	TBD	TBD	V
Instantaneous Forward Voltage ①	Each MOSFET I _S = 10A Intrinsic Diode ③	-	TBD	TBD	V
Reverse Recovery Time ①	Intrinsic Diode	-	-	280	nS
Leakage Current ①	Each MOSFET V ₊ = 70V	-	1.0	25	μA
PWM Frequency		225	250	275	KHz
V_{CC} SUPPLY CHARACTERISTICS					
Quiescent Bias Current	Analog Input = 6Vdc	-	43	TBD	mA
V _{CC} Voltage Range ①		9	12	16	V
INPUT SIGNAL CHARACTERISTICS ①					
Analog Input Voltage	Output A,B = 50% Duty Cycle	-	6	-	V
Analog Input Voltage	Output A = 100% Duty Cycle High	-	4	-	V
Analog Input Voltage	Output B = 100% Duty Cycle High	-	8	-	V
LOGIC CONTROL INPUTS ①					
Disable Input	Input Voltage LO	-	-	0.8	V
	Input Voltage HI	2.7	-	-	V
	Input Current (DISABLE = 0V)	-	-	-135	μA
HEN Input	Input Voltage LO	-	-	0.8	V
	Input Voltage HI	2.7	-	-	V
	Input Current (HEN = 0V)	-	-	-270	μA
SWITCHING CHARACTERISTICS ①					
	R _L = 100Ω				
Rise-Time		-	TBD	-	nS
Fall-Time		-	TBD	-	nS
Dead-Time		-	100	-	nS

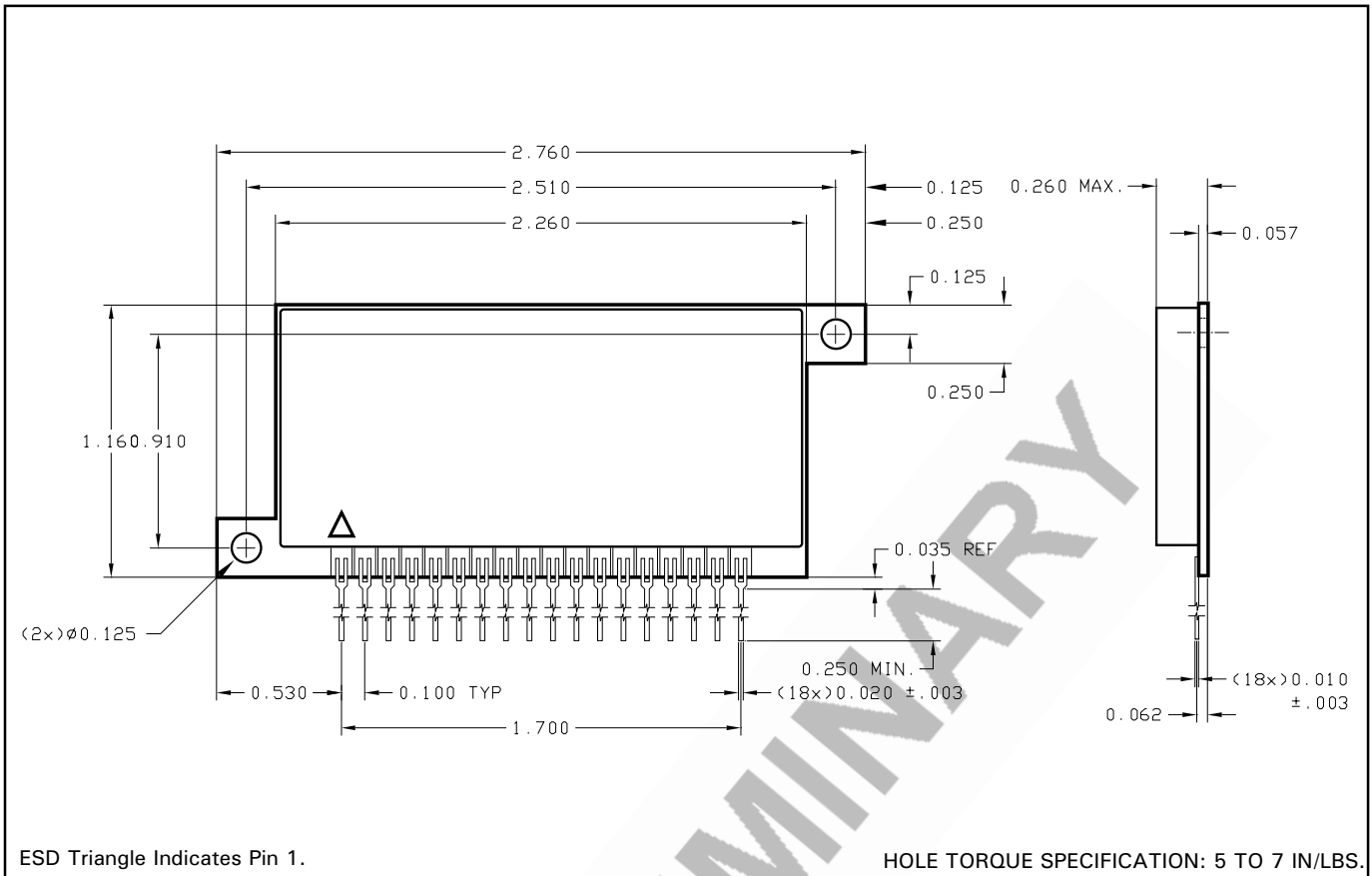
NOTES:

- ① Guaranteed by design but not tested. Typical parameters are representative of actual device performance but are for reference only.
- ② V_{CC} = +12V unless otherwise specified.
- ③ Measure using a 300μS pulse with a 2% Duty Cycle.
- ④ On Resistance is specified for the Internal MOSFET for Thermal Calculations. It does not include the package pin resistance.

TYPICAL PERFORMANCE CURVES



MECHANICAL SPECIFICATIONS



NOTE: ALL DIMENSIONS ARE ± 0.010 UNLESS OTHERWISE LABELED.

ORDERING INFORMATION

Part Number	Screening Level
MSK4224	Industrial

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